

Novel CMP Pad for Tungsten Polishing

ERC TeleSeminar March 24, 2005 John Bare, Program Director



Agenda

- Background on pad benefits, features, and architecture
- Current pad technology
- Pad performance
- Future pad technology



History and Philosophy

- Commercial goal create CMP polishing pad business
- Barrier entrenched technologies and suppliers difficult to displace
- Constraints Polyurethane IP field dominated by R&H
- Concept improve overall performance and lower CoO without copying existing technology
- Target users or applications for whom "one size fits all" approach is not the best → provide alternative to existing CMP pad
- R&D History many materials, surface treatments, composite structures examined



W CMP Generally Expected Performance

- 2,500 4,000 Å/min removal rate
- <5% WIWNU
- <20 particles added
- <200 Å Dishing
- <200 Å Erosion
- <100 Å/min oxide removal rate
- >1,000 polishing minutes pad life



Tungsten Polishing Pad Features and Benefits

Application Specific Pad

- Polyolefin foam pad
- Closed cell structure for surface texture
- No diamond conditioning
- Very low defects
- Long life
- Low Cost of Ownership



Pad Architecture



Cell structure and construction similar for all pads

Cell size ≈ 150 µm



Thermoplastic Foam Surface Pad Co-extruded Hard-cap Sub-pad Glue Layer Type A Mylar Interposer Glue Layer Type B



LECO Screening 12-inch Table Top Polisher

LECO Screening of Pad Materials



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DOE for polisher conditions Removal Rate as f(Down Force)

psiloQuest 3035 CMP Polishing Pad Tungsten Removal Rate as Function of Downforce for Various Table Speeds





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DOE for polisher conditions WIWNU as f(Down Force)

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DOE for polisher conditions WIWNU as f(Table Speed)

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[H₂O₂] and Slurry Dilution



Effect of H₂O₂ Concentration and Slurry Dilution on Removal Rate

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[H₂O₂] and Slurry Dilution

- Increasing $[H_2O_2]$ can increase Removal Rate
- Works very well at higher [H₂O₂] 4% H₂O₂ vs. typical 2%
- No increase in keyholing (coring)
- Increasing slurry dilution can decrease Cost of Ownership & environmental cost
- Works well with non-H₂O₂ slurry



TQ800 Evaluation

TQ800 Response to Aggressive Abuse from Polisher Settings and Temperature





W3870 Evaluation

W3870 Removal Rate and WIWNU with Fujimi FCW-1 Tungsten-Polishing Slurry





I ungsten Removal Rate and WIWNUW30352500-minute Marathon

Tungsten Removal Rate and WIWNU W3035 2500-minute commercial wafer run





Cross section of completed via Commercial wafer



- Excellent plug planarity and controlled recess.
- End-of-line device yield equivalent between outsourced CMP and existing qualified fab process.





Defectivity During CMP Marathon





Erosion with Fujimi slurry

Tungsten Polishing Pad Erosion Evaluation for 50 mil pad thickness Oxide Erosion as f(DF[7 & 5], TS[85 & 100], Oxidizer[80%, 60%, 50%])





Material Properties of Interest

Overall performance results from convergence of several parameters/properties

- Material
 - Some properties determined by composition of polymer material
 - Some properties determined by manufacturing process
- Cell Size
 - Typical cell size ~ 100 200 microns
 - Smaller cell size gives more, smaller land areas for pad-wafer contact
- Hardness
 - Hardness is f(density for similar starting material)
 - For given material, harder = denser = more land area
- Thermal Stability
 - Higher thermal stability improves lifetime
 - PE gives more thermal stability than EVA
- Additives/Filler
 - Increase effective hardness of pad for a given material
 - Change asperity size and distribution
 - Change Coefficient of Friction

John Bare



Summary Tungsten CMP Polishing Pads

- polyolefin pads alternative to polyurethane
- Balance of performance properties
 - RR, WIWNU, Dishing, Erosion, Defects
- Low Cost of Ownership
 - No diamond conditioning
 - Long pad life
 - Lower slurry consumption